

v02.0701

# HMC270MS8G

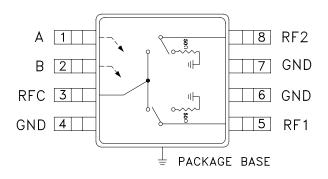
## GaAs MMIC SPDT SWITCH NON-REFLECTIVE, DC - 8.0 GHz

## Typical Applications

The HMC270MS8G is ideal for DC - 8.0 GHz applications:

- CATV
- MMDS & WirelessLAN
- Wireless Local Loop

### Functional Diagram



#### Features

Broadband Performance: DC - 8 GHz Very High Isolation: 45 dB @ 6 GHz Non-Reflective Design Low Cost MSOP-8 Package: 14.8 mm<sup>2</sup>

### **General Description**

The HMC270MS8G is a broadband non-reflective GaAs SPDT switch in an 8 lead MSOP grounded base surface mount plastic package. Covering DC to 8 GHz, the switch offers excellent isolation from 70 to 35 dB. The negative control voltage of -5 volts allows operation down to DC. If positive control is required along with high isolation, see the DC to 3.5 GHz HMC284MS8G non-reflective SPDT.

## **Electrical Specifications**, $T_A = +25^{\circ}$ C, With 0/-5V Control, 50 Ohm system

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz		0.8 1.0 1.5	1.2 1.7 2.4	dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	43 42 37 28	48 47 45 33		dB dB dB dB
Return Loss	"On State"	DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz	11 9 7	14 12 10		dB dB dB
Return Loss RF1, RF2	"Off State"	DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz	15 13 10	20 18 15		dB dB dB
Input Power for 1 dB Compression		0.5 - 8.0 GHz	20	23		dBm
Input third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 8.0 GHz	33	36		dBm
Switching Characteristics		DC - 8.0 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)				20 50		ns ns

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 12 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order Online at www.hittite.com

14



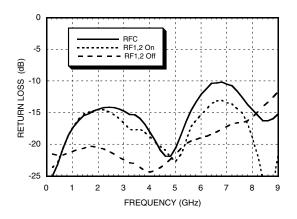
## HMC270MS8G

## GaAs MMIC SPDT SWITCH NON-REFLECTIVE, DC - 8.0 GHz

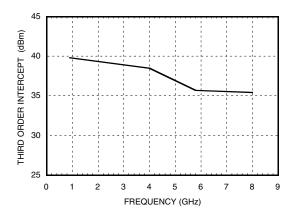
#### 0 -1 (qB) INSERTION LOSS -2 RF1 -3 RF2 -4 -5 0 1 2 3 4 5 6 7 8 9 FREQUENCY (GHz)

#### **Return Loss**

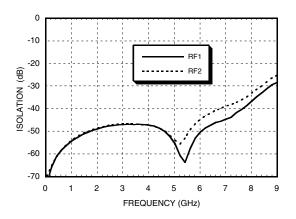
**Insertion Loss** 



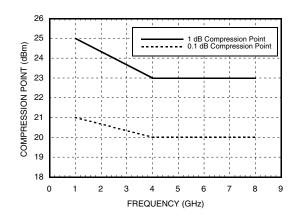
Input Third Order Intercept Point



## Isolation



#### 0.1 and 1 dB Input Compression Point



## **Control Voltages**

State	Bias Condition
Low	0 to -0.2V @ 10 uA Typ.
High	-5V @ 35 uA Typ. to -7V @ 100 uA Typ (±0.5 Vdc)

RFC, RF1, & RF2 should be at <100 mV DC potential. Otherwise, DC blocking capacitors are recommended. Choose value for lowest frequency of operation.

Do not "HOT" switch power levels >+13 dBm (Vctl = 0/-5Vdc)

#### Truth Table

Control Input		Signal Path State		
Α	В	RFC to RF1	RFC to RF2	
High	Low	ON	OFF	
Low	High	OFF	ON	

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 12 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order Online at www.hittite.com SWITCHES - SMI



## HMC270MS8G

EXPOSED GROUND PADDLE MUST BE CONNECTED TO RF/DC GROUND.

.060 1.52

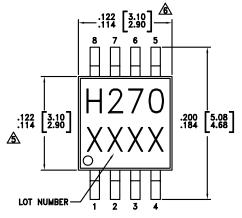
## GaAs MMIC SPDT SWITCH NON-REFLECTIVE, DC - 8.0 GHz

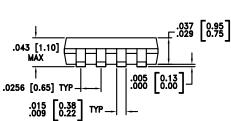
## Absolute Maximum Ratings

Max RF Input Power, VctI = -5V	+24 dBm
Control Voltage Range	+0.5 to -7.5 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

v02.0701

## **Outline Drawing**





NOTES.

.009 .003 0.08

- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- 3. LEADFRAME PLATING: Sn/Pb SOLDER

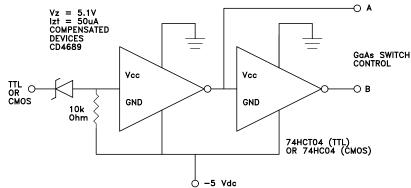
.050 1.27 .040 1.02

Ŧ

- LEADFRAME PLATING: Sn/Pb SOLDER
  DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
  ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED
  - TO PCB RF GROUND.

.031 0.80

### Suggested Driver Circuit for HMC270MS8G



Simple driver using inexpensive standard logic ICs provides fast switching using minimum DC current while translating from standard positive voltage TTL or CMOS logic to negative voltage GaAs IC logic.

> For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 12 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order Online at www.hittite.com

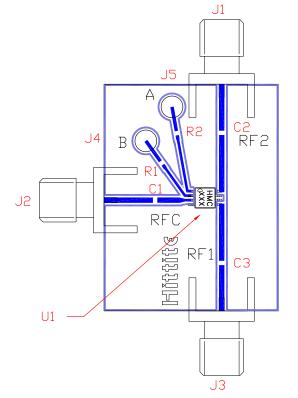
14



## HMC270MS8G

## GaAs MMIC SPDT SWITCH NON-REFLECTIVE, DC - 8.0 GHz

Eval Board Layout (Top View)



\*R1 = R2 = 100 Ohm. These are optional resistors.

## List of Materials

Item	Description
J1 - J3	PC Mount SMA Connector
J4 - J5	DC Pin
C1 - C3	Chip Capacitor, 0402 Pkg, choose value for lowest frequency of operation. PCBs are provided with 100 ~ 300 pF capacitors. User may jumper capacitor mounting gaps on PCB to allow operation to "DC".
R1 - R2	100 Ohm Resistor, 0402 Pkg.
U1	HMC270MS8G SPDT Switch
PCB*	102807 Evaluation PCB 2.0" x 2.6"
* Circuit Board Material: Rogers 4350	

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance and the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request. <mark>14</mark> ⊢